Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

## 2SC3267

# Power Amplifier Applications Power Switching Applications

- Low saturation voltage:  $V_{CE}$  (sat) = 0.5 V (max) @ $I_{C}$  = 2 A
- Complementary to 2SA1297

## Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector-base voltage      | $V_{CBO}$        | 20      | V    |
| Collector-emitter voltage   | V <sub>CEO</sub> | 20      | V    |
| Emitter-base voltage        | V <sub>EBO</sub> | 6       | V    |
| Collector current           | Ic               | 2       | Α    |
| Base current                | Ι <sub>Β</sub>   | 0.5     | Α    |
| Collector power dissipation | PC               | 400     | mW   |
| Junction temperature        | Tj               | 150     | °C   |
| Storage temperature range   | T <sub>stg</sub> | -55~150 | °C   |

# 1. EMITTER 2. COLLECTOR 3. BASE JEDEC — JEITA — TOSHIBA 2-4E1A

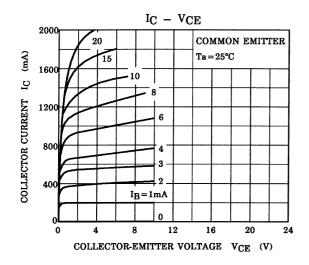
Weight: 0.13 g (typ.)

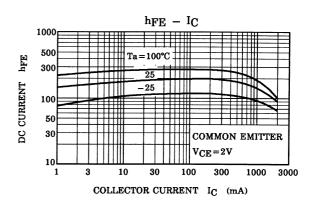
## **Electrical Characteristics (Ta = 25°C)**

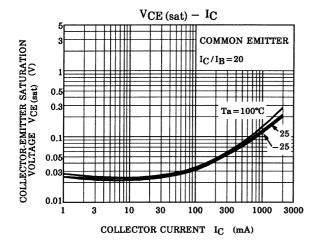
| Characteristics                      | Symbol                        | Test Condition                                        | Min | Тур. | Max  | Unit |
|--------------------------------------|-------------------------------|-------------------------------------------------------|-----|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>              | V <sub>CB</sub> = 20 V, I <sub>E</sub> = 0            | _   | _    | 0.1  | μΑ   |
| Emitter cut-off current              | I <sub>EBO</sub>              | V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0             | _   | _    | 0.1  | μА   |
| Collector-emitter breakdown voltage  | V (BR) CEO                    | $I_C = 10 \text{ mA}, I_B = 0$                        | 20  | _    | _    | V    |
| Emitter-base breakdown voltage       | V (BR) EBO                    | $I_E = 0.1 \text{ mA}, I_C = 0$                       | 6   | _    | _    | V    |
| DC current gain                      | h <sub>FE (1)</sub><br>(Note) | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA        | 120 | _    | 700  |      |
|                                      | h <sub>FE (2)</sub>           | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A           | 75  | _    | _    |      |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat)         | I <sub>C</sub> = 2 A, I <sub>B</sub> = 0.1 A          | _   | _    | 0.5  | V    |
| Base-emitter voltage                 | V <sub>BE</sub>               | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.1 A         | _   | _    | 0.85 | V    |
| Transition frequency                 | f <sub>T</sub>                | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A         | _   | 120  | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>               | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz | _   | 30   | _    | pF   |

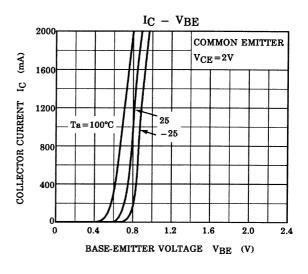
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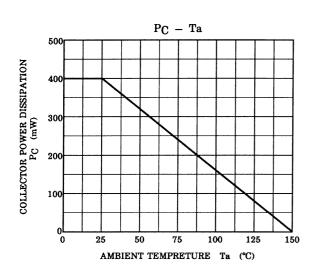
Note:  $h_{FE\ (1)}$  classification Y: 120~240, GR: 200~400, BL: 350~700

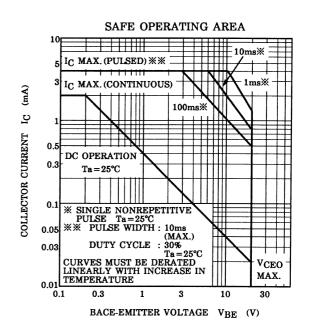












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